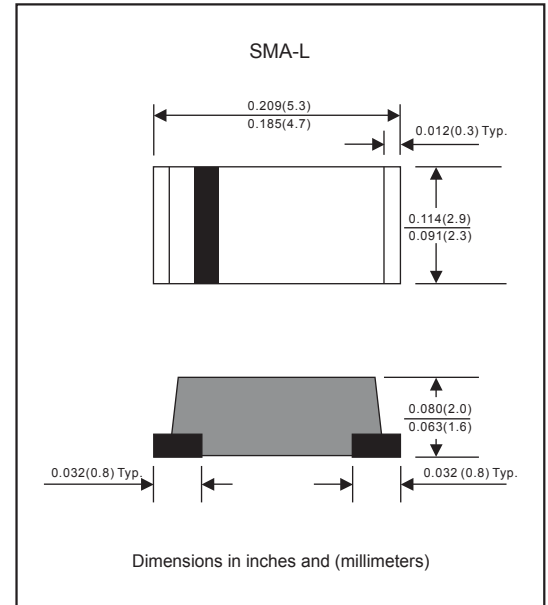


FEATURES

- * Batch process design, excellent power dissipation offers better reverse leakage current and thermal resistance.
- * Low profile surface mounted application in order to optimize board space.
- * Low power loss, high efficiency.
- * High current capability, low forward voltage drop.
- * High surge capability.
- * Ultra high-speed switching.
- * Lead-free parts meet environmental standards of MIL-STD-19500/228
- * RoHS product for packing code suffix "G"
Halogen free product for packing code suffix "H"

MECHANICAL DATA

Case: Molded plastic, DO-214AC / SMA-L
Epoxy: UL 94V-O rate flame retardant
Terminals: Solder plated, solderable per MIL-STD-750, Method 2026.
Mounting position: Any
Weight: Approximated 0.05 gram.



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

RATINGS		SYMBOL	FM120L	FM130L	FM140L	FM150L	FM160L	FM180L	FM1100L	FM1150L	UNIT
Marking Code			SS12	SS13	SS14	SS15	SS16	SS18	S110	S115	
Maximum Recurrent Peak Reverse Voltage		V _{RRM}	20	30	40	50	60	80	100	150	Volts
Maximum RMS Voltage		V _{RMS}	14	21	28	35	42	56	70	105	Volts
Maximum DC Blocking Voltage		V _{DC}	20	30	40	50	60	80	100	150	Volts
Maximum Average Forward Rectified Current		I _O	1.0								Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)		I _{FSM}	30								Amps
Typical Thermal Resistance (Note 2)		R _{θJA}	88								°C/W
Typical Junction Capacitance (Note 1)		C _J	120								pF
Operating Temperature Range		T _J	-55 to +125			-55 to +150					°C
Storage Temperature Range		T _{STG}	-55 to +150								°C
CHARACTERISTICS		SYMBOL	FM120L	FM130L	FM140L	FM150L	FM160L	FM180L	FM1100L	FM1150L	UNIT
Maximum Forward Voltage at 1.0A DC		V _F	0.50			0.70		0.85		0.92	Volts
Maximum Average Reverse Current at Rated DC Blocking Voltage	@T _J =25°C	I _R	0.5								mAmps
	@T _J =100°C		10								

NOTES:

1- Measured at 1 MHz and applied reverse voltage of 4.0 VDC.

2- Thermal Resistance From Junction to Ambient

RATING AND CHARACTERISTIC CURVES

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

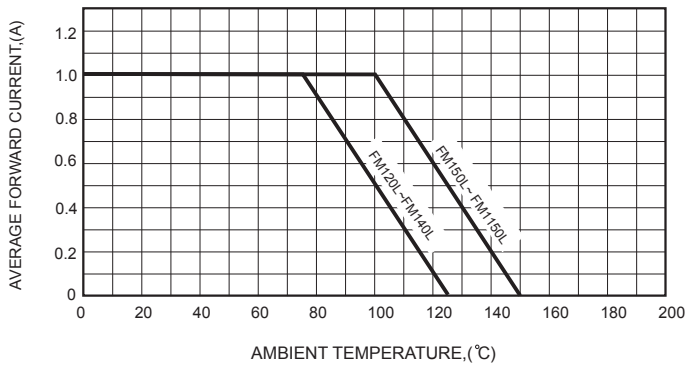


FIG.2-TYPICAL FORWARD CHARACTERISTICS

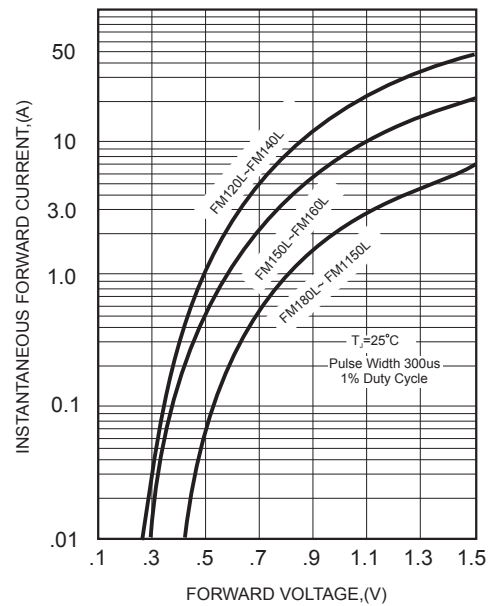


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

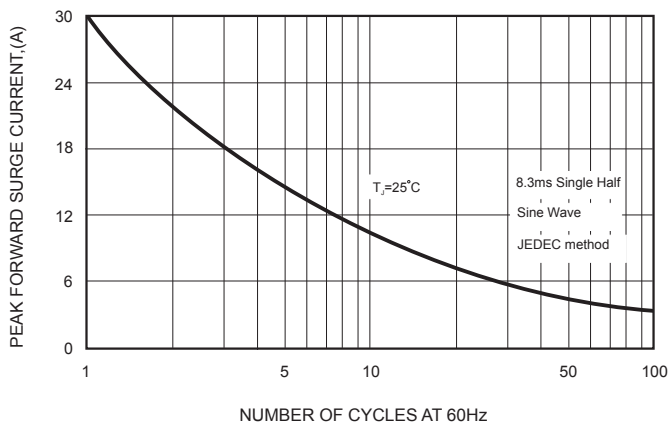


FIG.5 - TYPICAL REVERSE CHARACTERISTICS

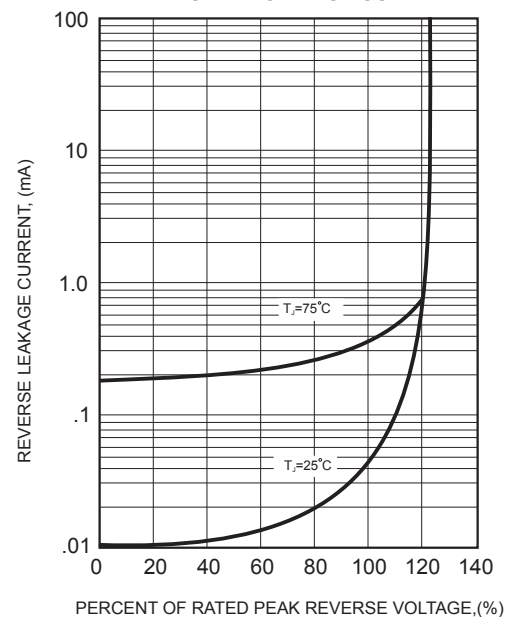


FIG.4-TYPICAL JUNCTION CAPACITANCE

